

Characteristics of a PV module

Manufacturer, model : **Longi Solar, LR4-72HBD-435M-glaze-new**

Data source : Longi 202002

STC power (manufacturer)	Pnom	435 Wp	Technology	Si-mono
Module size (W x L)	1.038 x 2.094	m ²	Rough module area	Amodule 2.17 m ²
Number of cells	2 x 72		Sensitive area (cells)	Acells N/A m ²
Specifications for the model (manufacturer or measurement data)				
Reference temperature	TRef	25 °C	Reference irradiance	GRef 1000 W/m ²
Open circuit voltage	Voc	49.1 V	Short-circuit current	Isc 11.36 A
Max. power point voltage	Vmpp	40.8 V	Max. power point current	Impp 10.66 A
=> maximum power	Pmpp	434.9 W	Isc temperature coefficient	mulsc 6.7 mA/°C

One-diode model parameters				
Shunt resistance	Rshunt	1000 ohm	Diode saturation current	IoRef 0.087 nA
Serie resistance	Rserie	0.27 ohm	Voc temp. coefficient	MuVoc -144 mV/°C
			Diode quality factor	Gamma 1.04
Specified Pmax temper. coeff.	muPMaxR	-0.35 %/°C	Diode factor temper. coeff.	muGamma 0.000 1/°C

Reverse Bias Parameters, for use in behaviour of PV arrays under partial shadings or mismatch				
Reverse characteristics (dark)	BRev	3.20 mA/V ²	(quadratic factor (per cell))	
Number of by-pass diodes per module		3	Direct voltage of by-pass diodes	-0.7 V

Model results for standard conditions (STC: T=25° C, G=1000 W/m², AM=1.5)				
Max. power point voltage	Vmpp	40.3 V	Max. power point current	Impp 10.82 A
Maximum power	Pmpp	436.1 Wc	Power temper. coefficient	muPmpp -0.34 %/°C
Efficiency(/ Module area)	Eff_mod	20.1 %	Fill factor	FF 0.782
Efficiency(/ Cells area)	Eff_cells	N/A %		

